

JAN2N5582

JAN2N5582 Information



t Number	JAN2N5582
nufacturer	Microsemi Corporation
egory	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
cription	TRANS NPN 50V 0.8A TO46
kage	TO-206AB, TO-46-3 Metal Can
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N5582 Specifications

Manufacturer Part Number	JAN2N5582
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-206AB, TO-46-3 Metal Can
Series	Military, MIL-PRF-19500/423
Transistor Type	NPN
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	1V @ 50mA, 500mA
Current - Collector Cutoff (Max)	10μA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 150mA, 10V
Power - Max	500mW
Frequency - Transition	-
Operating Temperature	-55°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-206AB, TO-46-3 Metal Can
Supplier Device Package	TO-46-3
	Report errors?

JAN2N5582 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N5582, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com